NSN 5961-01-619-5741

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View Online at https://aerobasegroup.com/nsn/5961-01-619-5741 **Inclosure Material:** Metal **Overall Length:** 32.0 millimeters **Terminal Length:** 8.5 millimeters **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: E8 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Terminal Circle Diameter:** 6.0 millimeters **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 11.0 millimeters Thready Qty Per Inch (tpi): 32 **Thread Size:** 0.190 inches Voltage Rating In Volts Per Characteristic: 1.55 forward voltage, dc and 1600.0 reverse supression voltage **Current Rating Per Characteristic:** 40.0 amperes forward current, total rms **Power Rating Per Characteristic:** 33.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 180.0 degrees celsius ambient air **Product Name:** Diode, anode-stud **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug

Shelf Life: N/a

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No

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